

# **QT-Brightek PLCC Series**

## **PLCC2 LED**

**Part No.: QBLP670 Series**

Product: QBLP670_series	Date: August 07, 2018	Page 1 of 12
	Version# 3.4	

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## Introduction

**Feature:**

- Package in tape and reel
- Ultra bright reflector type PLCC2 LED
- InGaN technology for IB/IG/UV
- AlInGaP technology for R/AG/Y/O/S
- 120 degree viewing angle

**Description:**

These ultra bright reflector type PLCC2 LEDs have a height profile of 1.90mm. Combination of high brightness output and robust package, these LEDs are ideal for architecture lighting, status indication, and industrial equipment lighting applications.

**Application:**

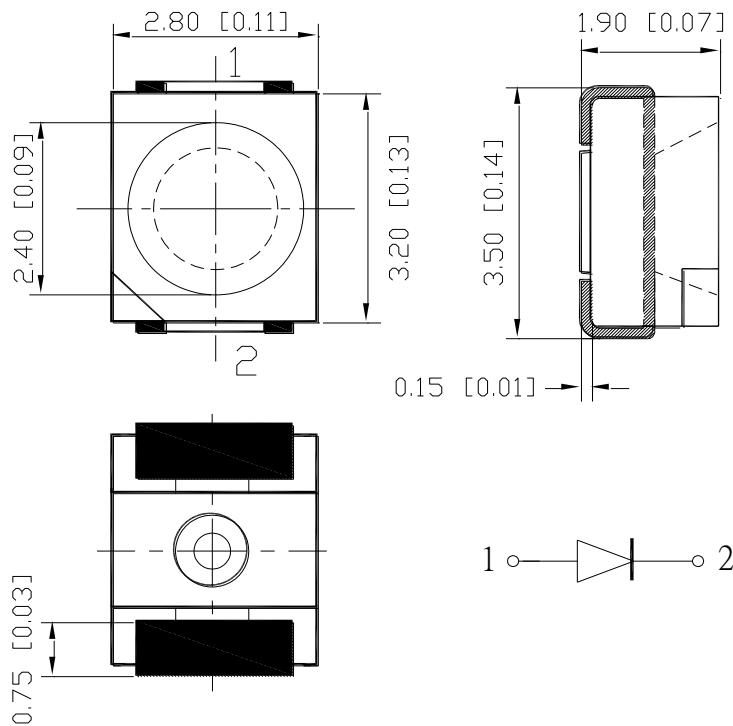
- Status indication
- Industrial equipment backlighting
- Architecture lighting

**Certification & Compliance:**

- TS16949
- ISO9001
- RoHS Compliant



**Dimension:**



Units: mm / tolerance = +/-0.2mm

**Electrical / Optical Characteristic (Ta=25 °C)**

Product	Color	I <sub>F</sub> (mA)	V <sub>F</sub> (V)		λ <sub>D</sub> (nm) / λ <sub>P</sub> (nm) for UV			I <sub>V</sub> (mcd) / I <sub>e</sub> (mW/sr) for UV	
			Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.
QBLP670-IB	Blue	20	3.1	3.7	465	470	475	100	210
QBLP670-IG	True Green	20	3.1	3.7	520	525	530	500	900
QBLP670-UV	UV	20	3.2	3.7	400	405	410	2.1	3.5
QBLP670-R	Red	20	2.0	2.5	615	620	630	125	230
QBLP670-AG	Yellow Green	20	2.0	2.5	565	570	576	40	80
QBLP670-Y	Yellow	20	2.0	2.5	585	590	595	125	210
QBLP670-O	Orange	20	2.0	2.5	600	605	612	160	240
QBLP670-S	Deep Red	20	2.0	2.5	630	640	650	50	80

**Absolute Maximum Rating**

Material	P <sub>d</sub> (mW)	I <sub>F</sub> (mA)	I <sub>FP</sub> (mA)*	V <sub>R</sub> (V)	T <sub>OP</sub> (°C)	T <sub>ST</sub> (°C)	T <sub>SO L</sub> (°C)**
InGaN (IB/IG/UV)	120	30	100	5	-40 ~ +85	-40 ~ +100	260
AllnGaP (R/AG/Y/O/S)	75	30	125	5	-40 ~ +85	-40 ~ +100	260

\*Duty 1/8 @ 1KHz

\*\*IR Reflow for no more than 10 sec @ 260 °C

**Forward Voltage V<sub>F</sub> for AllnGaP @ I<sub>F</sub>=20mA**

Bin	Min.	Max.	Unit
□	1.7	2.5	V

**Forward Voltage V<sub>F</sub> for InGaN @ I<sub>F</sub>=20mA**

Bin	Min.	Max.	Unit
f	2.8	3.1	V
g	3.1	3.4	
h	3.4	3.7	

**Dominant Wavelength  $\lambda_D$  for Blue @  $I_F=20mA$**

Bin	Min.	Max.	Unit
G	465	467.5	nm
H	467.5	470	
I	470	472.5	
J	472.5	475	

**Dominant Wavelength  $\lambda_D$  for Green @  $I_F=20mA$**

Bin	Min.	Max.	Unit
U	520	522.5	nm
V	522.5	525	
W	525	527.5	
X	527.5	530	

**Dominant Wavelength  $\lambda_D$  for Red @  $I_F=20mA$**

Bin	Min.	Max.	Unit
s	615	620	nm
t	620	625	
u	625	630	

**Dominant Wavelength  $\lambda_D$  for Yellow Green @  $I_F=20mA$**

Bin	Min.	Max.	Unit
h	565	568	nm
i	568	572	
j	572	576	

**Dominant Wavelength  $\lambda_D$  for Yellow @  $I_F=20mA$**

Bin	Min.	Max.	Unit
m	585	590	nm
n	590	595	

**Dominant Wavelength  $\lambda_D$  for Orange @  $I_F=20mA$**

Bin	Min.	Max.	Unit
p	600	605	nm
q	605	610	

**Dominant Wavelength  $\lambda_D$  for Deep Red @  $I_F=20mA$**

Bin	Min.	Max.	Unit
v	630	635	nm
w	635	650	

**Peak Wavelength  $\lambda_P$  for UV @  $I_F=20mA$**

Bin	Min.	Max.	Unit
G	400	405	nm
H	405	410	

**Luminous Intensity  $I_V$  @  $I_F=20mA$**

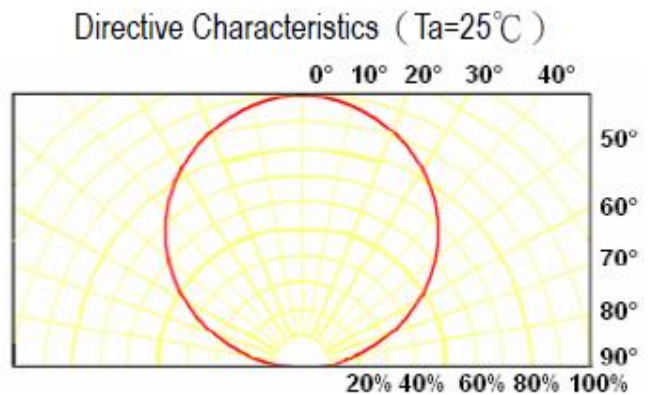
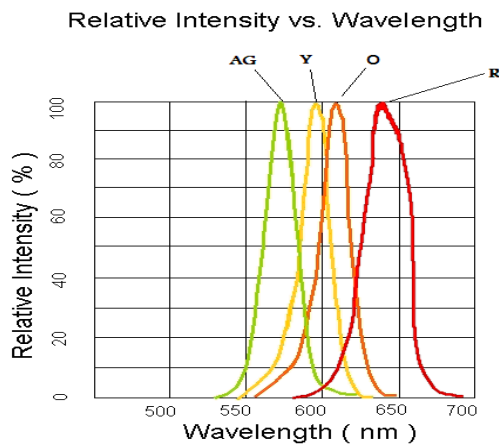
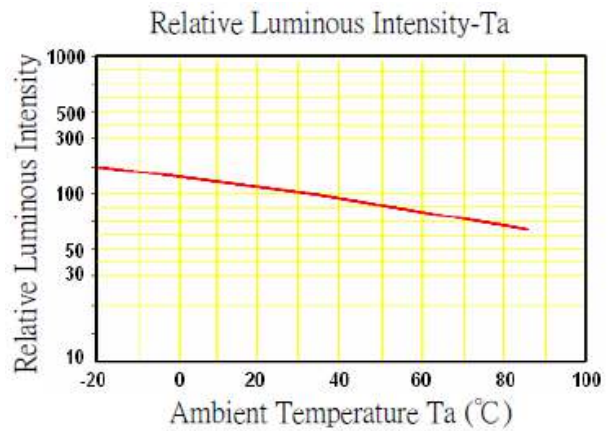
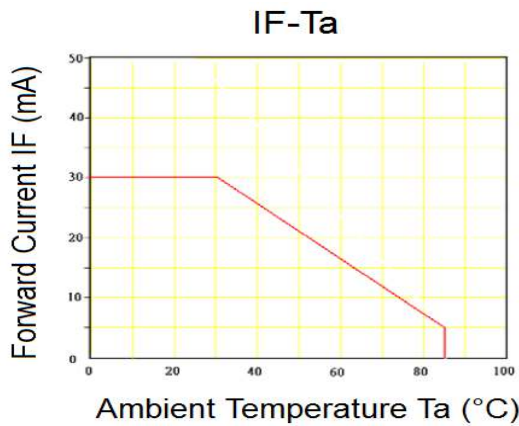
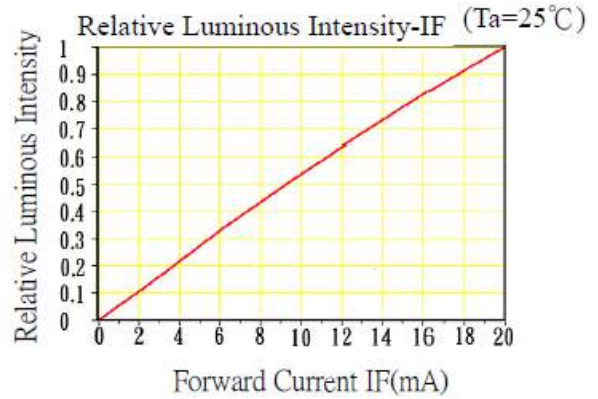
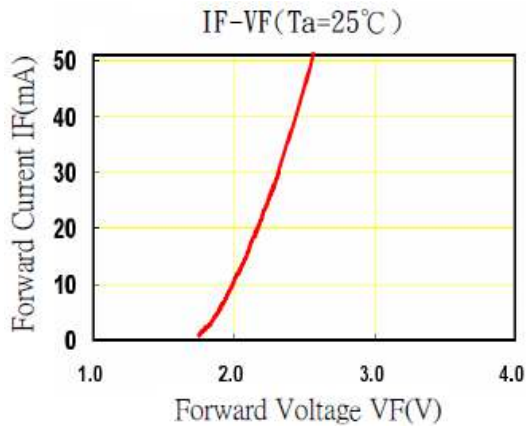
Bin	Min.	Max.	Unit
F	40	50	mcd
G	50	63	
H	63	80	
I	80	100	
J	100	125	
K	125	160	
L	160	200	
M	200	250	
N	250	320	
O	320	400	
P	400	500	
Q	500	630	
R	630	800	
S	800	1000	
T	1000	1250	
U	1250	1600	

**Radiant Intensity  $I_e$  for UV @  $I_F=20mA$**

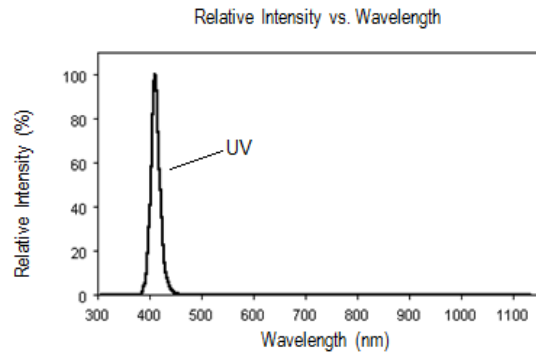
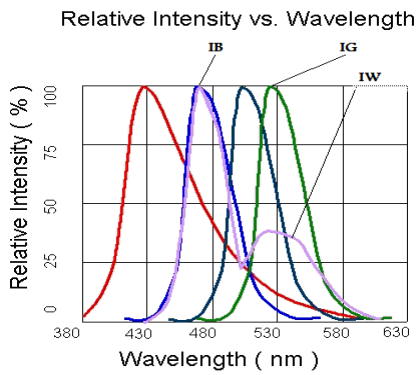
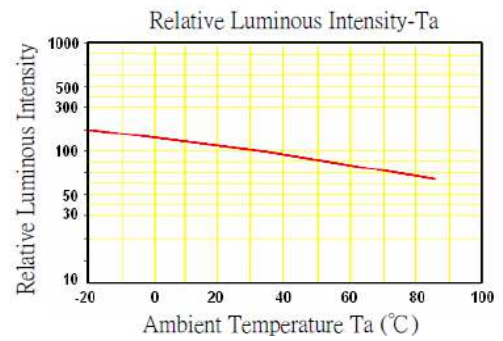
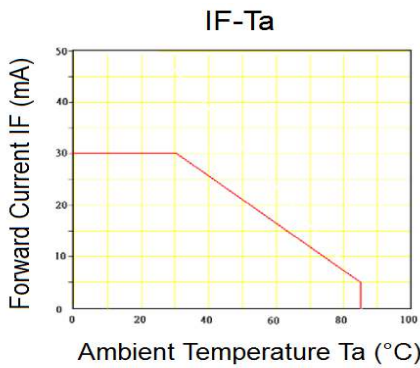
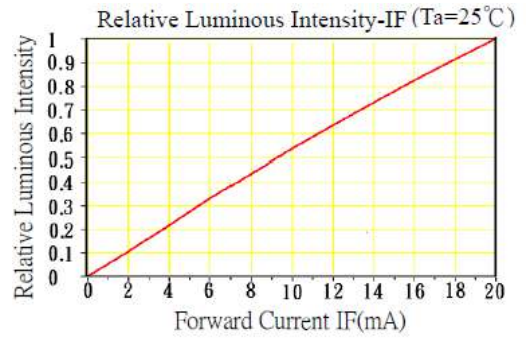
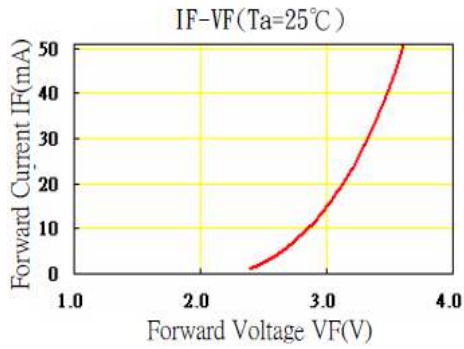
Bin	Min.	Max.	Unit
E	2.10	2.60	mW/sr
F	2.60	3.10	
G	3.10	3.60	
H	3.60	4.10	
I	4.10	4.60	

**Characteristic Curves**

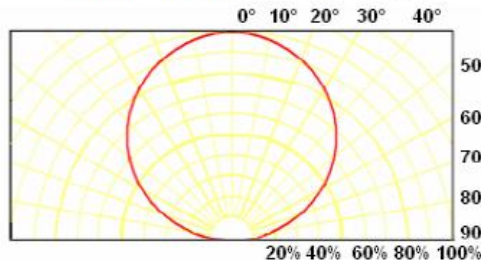
AllnGaP (R/AG/Y/O/S)



InGaN (IB/IG/UV)



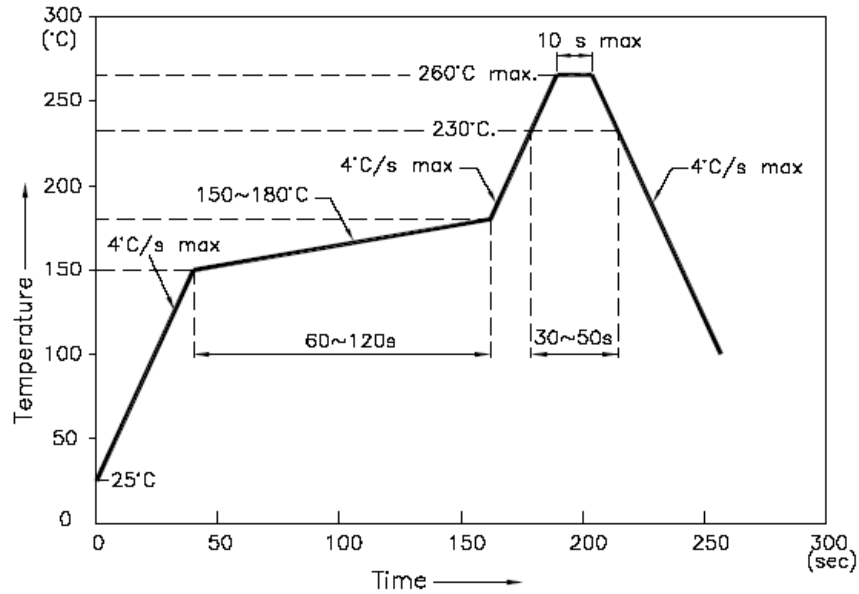
Directive Characteristics (Ta=25°C)



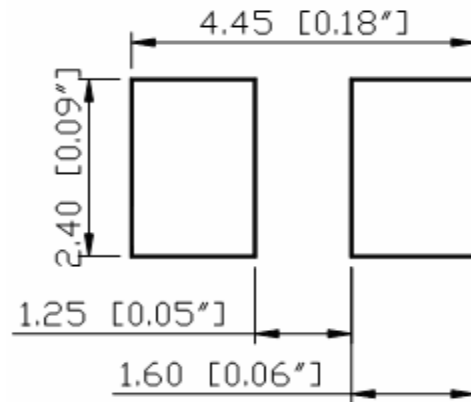


## Solder Profile & Footprint

- Recommended tin solder specifications: melting temperature in the range of 178~192 °C
- The recommended lead free reflow soldering profile is as follows (temperatures indicated are as measured on the surface of the LED resin):



### RECOMMEND PADLAYOUT



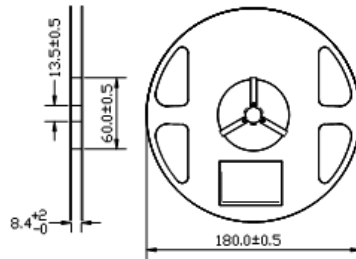
Units: mm

tolerance: +/- 0.1mm

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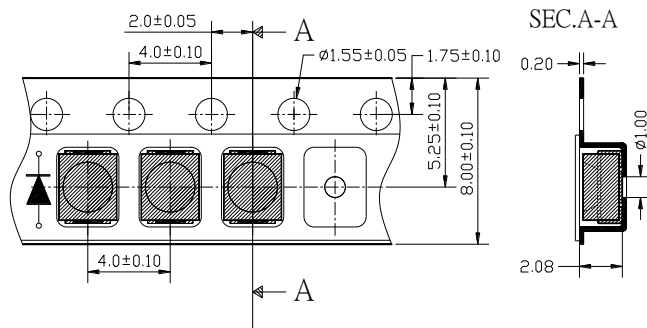
## Packing

Reel Dimension:



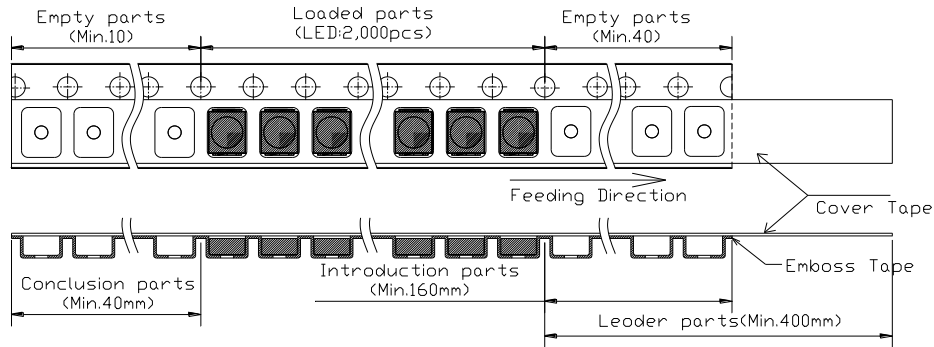
Unit: mm

Tape Dimension:

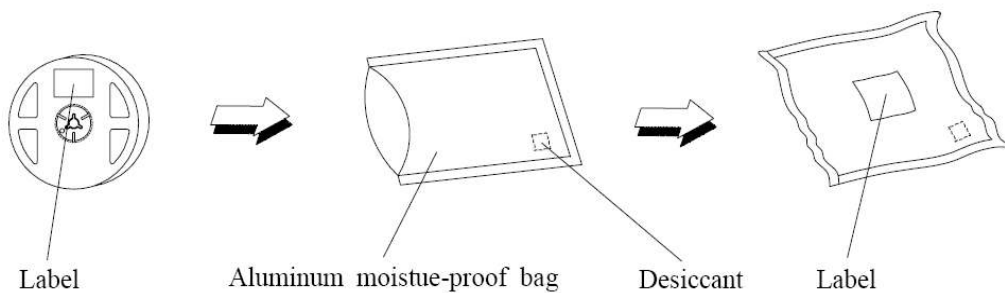


Unit: mm

Arrangement of Tape:



Packaging Specification:



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**Labeling**



Part No: \_\_\_\_\_  
 Customer P/N: \_\_\_\_\_  
 Item: \_\_\_\_\_  
 Q'ty: \_\_\_\_\_  
 Vf: \_\_\_\_\_  
 Iv: \_\_\_\_\_  
 WI: \_\_\_\_\_  
 Date: \_\_\_\_\_

**Made in China**

**Ordering Information**

Part #	Orderable Part #	Spec Range	Quantity per reel
QBLP670-IB	QBLP670-IB	Iv=210mcd typ. @ 20mA/ λ <sub>D</sub> =465nm to 475nm	2,000 units
QBLP670-IG	QBLP670-IG	Iv=900mcd typ. @ 20mA/ λ <sub>D</sub> =520nm to 530nm	2,000 units
QBLP670-UV	QBLP670-UV	Iv=3.5mW/sr typ. @ 20mA/ λ <sub>P</sub> =400nm to 410nm	2,000 units
QBLP670-R	QBLP670-R	Iv=230mcd typ. @ 20mA/ λ <sub>D</sub> =615nm to 630nm	2,000 units
QBLP670-AG	QBLP670-AG	Iv=80mcd typ. @ 20mA/ λ <sub>D</sub> = 565nm to 576nm	2,000 units
QBLP670-Y	QBLP670-Y	Iv=210mcd typ. @ 20mA/ λ <sub>D</sub> =585nm to 595nm	2,000 units
QBLP670-O	QBLP670-O	Iv=240mcd typ. @ 20mA/ λ <sub>D</sub> = 600nm to 612nm	2,000 units
QBLP670-S	QBLP670-S	Iv=80mcd typ. @ 20mA/ λ <sub>D</sub> =630nm to 650nm	2,000 units

## Revision History

Description:	Revision #	Revision Date
New Release of QBLP670_series	V1.0	09/20/2010
Specification Updates	V2.0	02/03/2011
Amend specification	V2.1	06/01/2011
Green Brightness Updates	V2.2	07/19/2011
Specification Updates	V2.3	01/05/2012
Update Format	V2.4	03/19/2012
Spec updates/ label updates	V3.0	01/30/2013
Add Deep Red Wavelength Bin	V3.1	09/30/2013
Update and add bin info for UV / Update orange min. brightness	V3.2	02/09/2015
Update operating and storage temperature	V3.3	03/09/2016
Update logo and the optical output power to mW/sr for UV	V3.4	08/07/2018

## Disclaimer

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.